

NS-FH-532/1-30W

**PICOSECOND PULSED LASER AT 532nm**

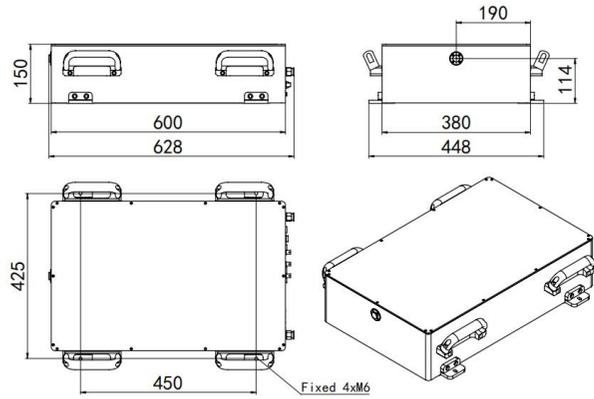
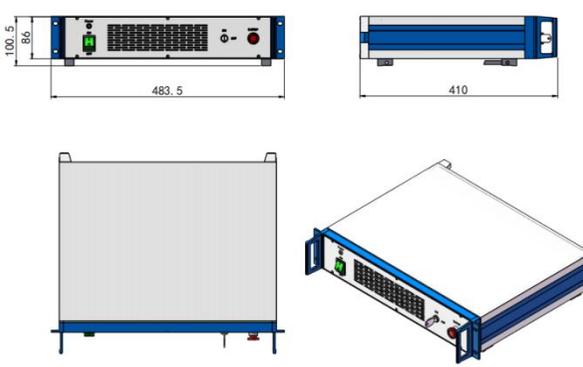
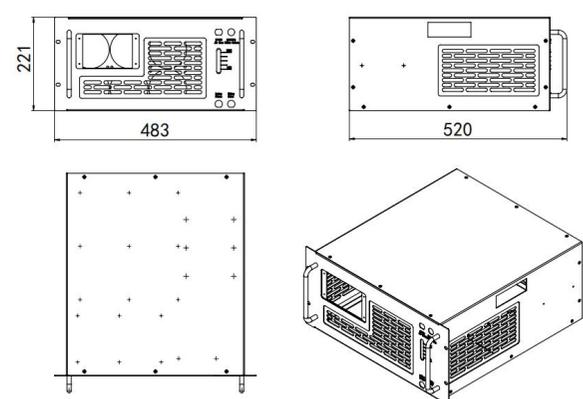
Nanosecond pulsed laser at 532nm is made features of short pulse duration, high repetition rate, high stability and good beam quality, which is used in sapphire marking, ceramic cutting, semiconductor cutting, film scribing, physics experiment, etc.



SPECIFICATIONS

Wavelength (nm)	532±1
Operating mode	Pulsed
Average power (W) <sup>1</sup>	1-30
Single pulse energy (uJ)	100µJ@200kHz; 30µJ@1MHz; 20µJ@1.5MHz
Rep. rate <sup>2</sup>	0.2-10MHz
Pulse duration (ns) <sup>3</sup>	2-10@1.5MHz
Peak power (MW)	1-20
Ave power stability (rms, 4 hours±3°C)	<2%, <1%
Warm-up time (minutes)	<10
Transverse mode	TEM <sub>00</sub>
M <sup>2</sup>	<1.3
Beam divergence, full angle (mrad)	<1
Beam diameter at the aperture (1/e <sup>2</sup> ,mm)	<3
Polarization ratio	>100:1 Horizontal
Beam height from base plate (mm)	114
Cooled method	Water cooled
Operating temperature (°C)	10-35
Power supply (100-240VAC)	RAD1PS
Expected lifetime (hours)	>10000



LASER HEAD (DRIVER Integrated)	POWER SUPPLY	WATER CHILLER
 <p>628 (L)×448 (W) ×150 (H) mm<sup>3</sup>,55kg</p>	 <p>410 (L) ×483.5 (W) ×110.5 (H) mm<sup>3</sup>,4.5 kg</p>	 <p>520 (L) ×483 (W) ×221 (H) mm<sup>3</sup>,22kg</p>

- 1 One fixed value between 1-30W.
- 2 Rep.rate range available on request.
- 3 Pulse width range available on request.

NS-FH-1064/1-60W

### NANOSECOND PULSED LASER AT 1064nm

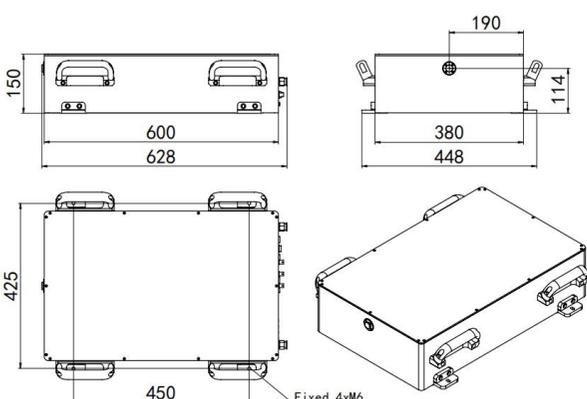
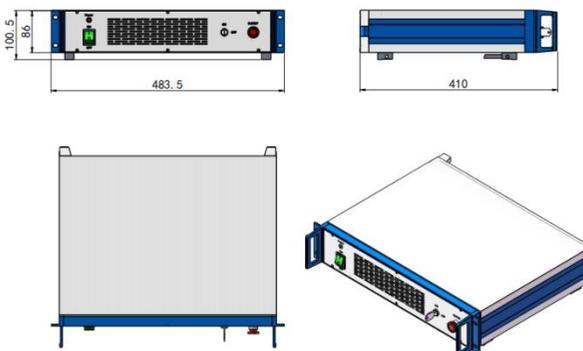
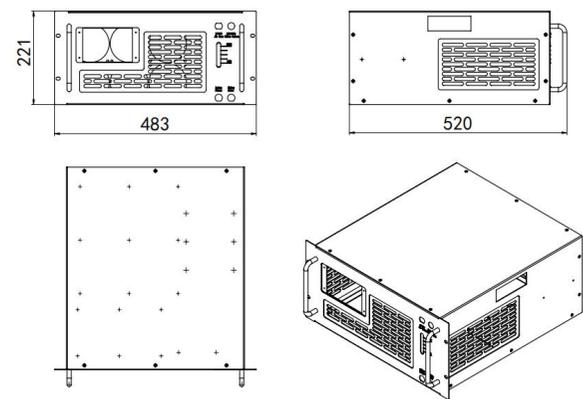
Ninosecond pulsed laser at 1064nm is made features of short pulse duration, high repetition rate, high stability and good beam quality, which is used in sapphire marking, ceramic cutting, semiconductor cutting, film scribing, physics experiment, etc.



#### SPECIFICATIONS

Wavelength (nm)	1064±1
Average power (W) <sup>1</sup>	1-60
Single pulse energy (uJ)	200µJ@200kHz; 60µJ@1MHz; 40µJ@1.5MHz
Rep. Rate <sup>2</sup>	0.2-10MHz
Pulse duration (ns) <sup>3</sup>	2-10ns@1.5MHz
Peak power (MW)	1-20
Ave power stability (rms, 4 hours±3°C)	<2%, <1%
Warm-up time (minutes)	<10
Transverse mode	TEM00
Beam divergence, full angle (mrad)	<1
Beam diameter at the aperture (1/e2,mm)	<3
M2	<1.3
Polarization ratio	>100:1 Vertical
Beam height from base plate (mm)	114
Cooled method	Water cooled
Operating temperature (°C)	15-35
Power supply (100-240VAC)	RAD1PS
Expected lifetime (hours)	>10000



LASER HEAD (DRIVER Integrated)	POWER SUPPLY	WATER CHILLER
 <p>628 (L)×448 (W) ×150 (H) mm<sup>3</sup>,55kg</p>	 <p>410 (L) ×483.5 (W) ×110.5 (H) mm<sup>3</sup>,4.5 kg</p>	 <p>520 (L) ×483 (W) ×221 (H) mm<sup>3</sup>,22kg</p>

- 1 One fixed value between 1-60W.
- 2 Rep.rate range available on request.
- 3 Pulse width range available on request.